NSN 5962-01-346-1904

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View Online at https://aerobasegroup.com/nsn/5962-01-346-1904	
Overall Length:	
1.060 inches	
Overall Height:	
0.400 inches	
Body Length:	
1.060 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.130 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
2.0 watts	
Operating Tempurature Range:	
-55.0/+125.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Receiving set, radar an/apr-47	
Features Provided:	
Hermetically sealed and burn in and bipolar and monolithic	
Inclosure Material:	
Ceramic	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
14 input	
Case Outline Source And Designator:	
D-8 mil-m-38510	
Current Rating Per Characteristic:	
90.00 milliamperes supply	
Terminal Surface Treatment:	
Solder	
Product Name:	
And-or gate array	
Voltage Rating And Type Per Characteristic:	

Time Rating Per Chacteristic:

45.00 nanoseconds propagation delay

-0.5 volts power source and 12.0 volts power source

Memory Device Type:

Programmable

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Test	Data	Document	ŀ
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96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

20 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0